

DATA SHEET

**ELECTROSTATIC DISCHARGE
PROTECTION DEVICES**

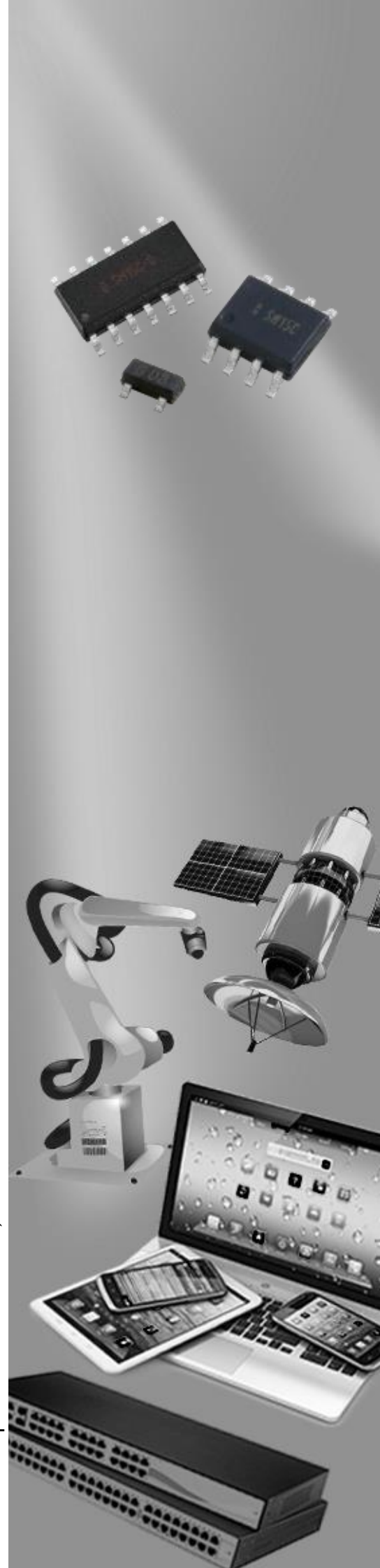
INDUSTRIAL / CONSUMER

SET23AXXL02 series

RoHS compliant & Halogen free



Product specification— March 20, 2021 V.2



Electrostatic Discharged Protection Devices (ESD) Data Sheet

Description

Brightking's SET23AXXL02 series are designed to protect components which are connected to data and transmission lines from voltage surges caused by electrostatic discharge (ESD), electrical fast transients (EFT) and lightning. TVS diodes are characterized by their high surge capability, low operating and clamping voltages, and fast response time. This makes them ideal for use as board level protection of sensitive semiconductor components. The low profile SOT-23 package allows flexibility in the design of crowded circuit boards.

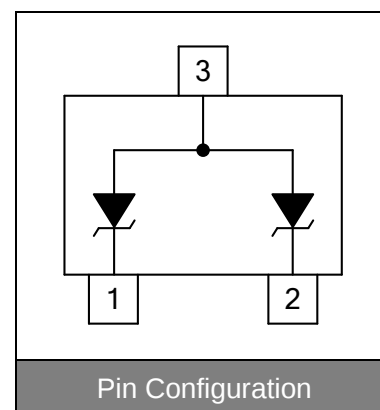


Contact : $\pm 30\text{kV}$
Air : $\pm 30\text{kV}$



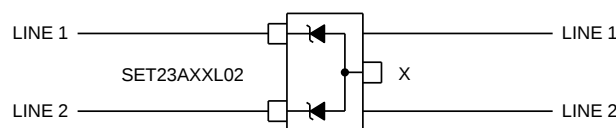
Features

- IEC61000-4-2 ESD 30KV Air, 30KV contact compliance
ESD 15KV Air, 8KV contact compliance for SET23A36L02
- SOT-23 surface mount package
- Protects one bidirectional line or two unidirectional lines
- Working voltage: 3.3V, 5V, 12V, 15V, 24V and 36V
- Low leakage current
- Low operating and clamping voltages
- Solid-state silicon avalanche technology
- Lead Free/RoHS compliant
- Solder reflow temperature: Pure Tin-Sn, 260~270°C
- Flammability rating UL 94V-0
- Meets MSL level 1, per J-STD-020

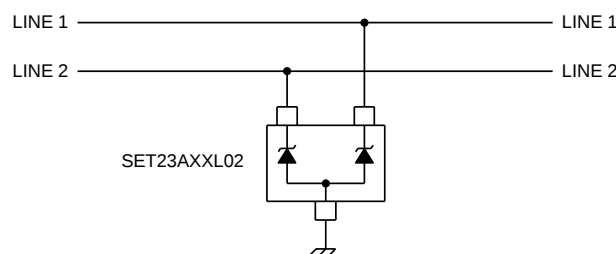


Applications

- Cellular handsets and accessories
- Personal digital assistants (PDA's)
- Portable instrumentation
- Set Top Box (STB)
- Servers, notebook, and desktop PC
- Wireless bus protection
- RS-232, RS-422, RS-423 protection



Bidirectional Protect Line



Unidirectional Protect Lines

Maximum Ratings

Rating	Symbol	Value	Unit
ESD voltage (Contact discharge)	V_{ESD}	± 8	kV
ESD voltage (Air discharge)		± 15	
Storage & operating temperature range	$T_{\text{STG}}, T_{\text{J}}$	-55~+150	°C

Electrical Characteristics ($T_J=25^{\circ}\text{C}$)

SET23A03L02 (Marking: B 03C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				3.3	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1\text{mA}$	4			V
Reverse leakage current	I_R	$V_R=3.3\text{V}$ each I/O pin			125	μA
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=1\text{A}$			7	V
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=15\text{A}$			15	V
Peak Pulse Current($t_p=8/20\mu\text{s}$)	I_{PP}				15	A
Off state junction capacitance	C_J	0Vdc, f=1MHz Between I/O pins and GND		300		pF

SET23A05L02 (Marking: B 05C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				5	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1\text{mA}$	6			V
Reverse leakage current	I_R	$V_R=5\text{V}$ each I/O pin			5	μA
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=1\text{A}$			9.8	V
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=15\text{A}$			20	V
Peak Pulse Current($t_p=8/20\mu\text{s}$)	I_{PP}				15	A
Off state junction capacitance	C_J	0Vdc, f=1MHz Between I/O pins and GND		220		pF

SET23A12L02-E18 (Marking: B 12C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				12	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1\text{mA}$	13.3			V
Reverse leakage current	I_R	$V_R=12\text{V}$ Each I/O pin			1	μA
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=1\text{A}$			19	V
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=10\text{A}$			27	V
Peak Pulse Current($t_p=8/20\mu\text{s}$)	I_{PP}				18	A
Off state junction capacitance	C_J	0Vdc, f=1MHz Between I/O pins and GND		100		pF

Electrical Characteristics ($T_J=25^{\circ}\text{C}$)

SET23A15L02 (Marking: B 15C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				15	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1\text{mA}$	16.7			V
Reverse leakage current	I_R	$V_R=15\text{V}$ each I/O pin			1	μA
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=1\text{A}$			24	V
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=10\text{A}$			30	V
Peak Pulse Current($t_p=8/20\mu\text{s}$)	I_{PP}				10	A
Off state junction capacitance	C_J	0Vdc, f=1MHz Between I/O pins and GND		90		pF

SET23A24L02 (Marking: B 24C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				24	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1\text{mA}$	26.7			V
Reverse leakage current	I_R	$V_R=24\text{V}$ each I/O pin			1	μA
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=1\text{A}$			43	V
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=5\text{A}$			49	V
Peak Pulse Current($t_p=8/20\mu\text{s}$)	I_{PP}				6	A
Off state junction capacitance	C_J	0Vdc, f=1MHz Between I/O pins and GND		80		pF

SET23A36L02 (Marking: B 36C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				36	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1\text{mA}$	40			V
Reverse leakage current	I_R	$V_R=36\text{V}$ each I/O pin			1	μA
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=1\text{A}$			51	V
Clamping voltage ($t_p=8/20\mu\text{s}$)	V_C	$I_{PP}=5\text{A}$			76.8	V
Peak Pulse Current($t_p=8/20\mu\text{s}$)	I_{PP}				5	A
Off state junction capacitance	C_J	0Vdc, f=1MHz Between I/O pins and GND		70		pF

Typical Characteristics Curves

Figure 1. Power Derating Curve

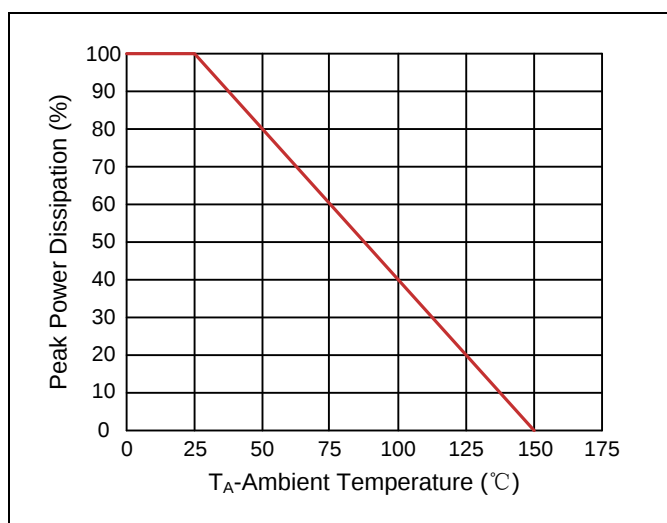


Figure 2. Pulse Waveforms

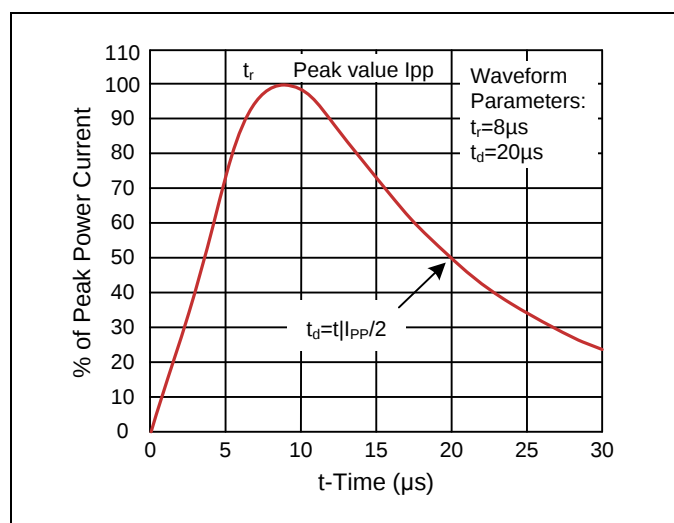


Figure 3. Forward Voltage vs. Forward Current

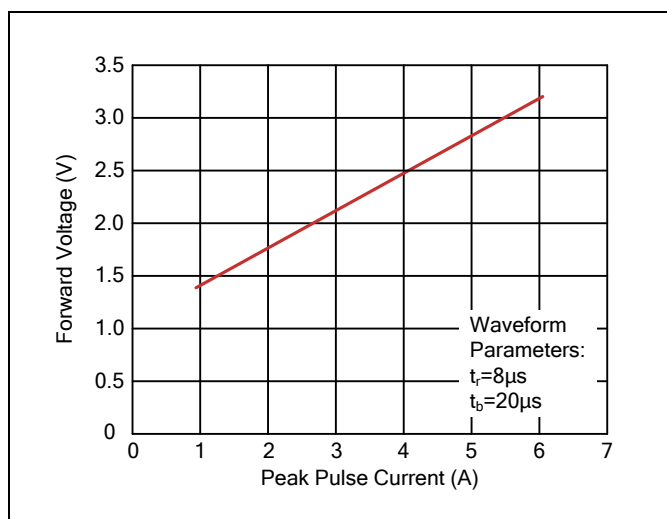
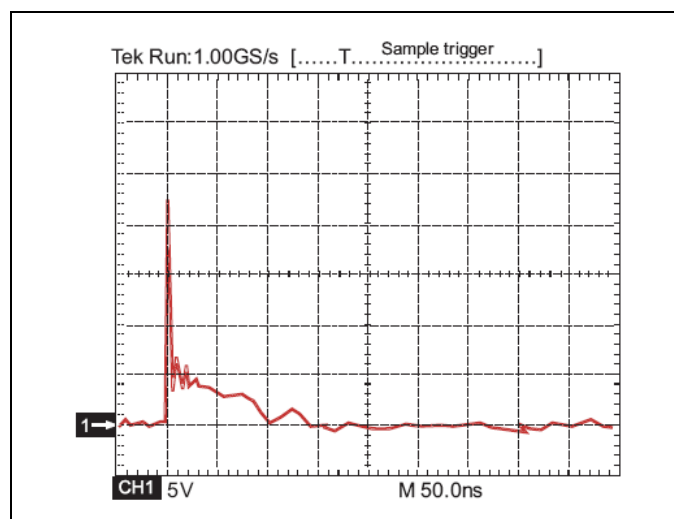
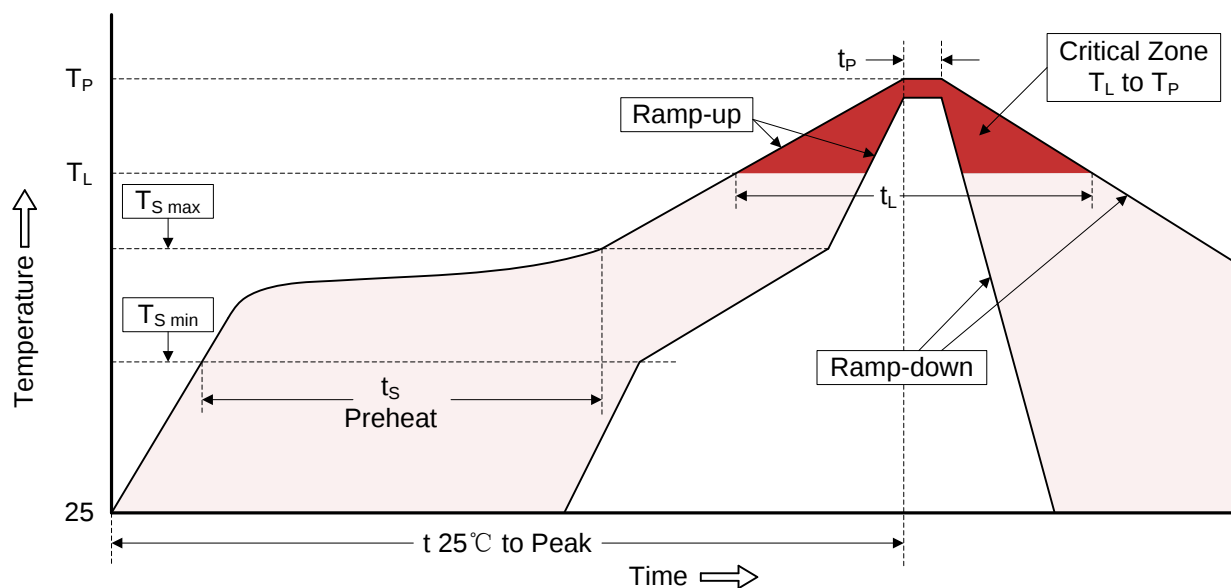


Figure 4. ESD Clamping(8kV Contact IEC61000-4-2)



Recommended Soldering Conditions

Reflow Soldering



Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	3°C/second max.
Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_s)	150°C 200°C 60-180 seconds
$T_{S\ max}$ to T_L -Ramp-up Rate	3°C/second max.
Time maintained above: -Temperature (T_L) -Time (t_L)	217°C 60-150 seconds
Peak Temperature (T_P)	260°C
Time within 5°C of actual Peak Temperature (t_P)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

Dimensions (SOT-23)

Symbol	Dimension			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.08	0.18	0.003	0.007
B	0.15	-	0.006	-
C	-	0.13	-	0.005
D	0.89	1.09	0.035	0.043
E	2.80	3.05	0.110	0.120
F	1.90		0.075	
G	0.95		0.037	
H	1.19	1.40	0.047	0.055
I	2.10	2.49	0.083	0.098
J	0.35	0.50	0.014	0.020

Recommended Soldering Pad Layout

Packaging

Tape	Symbol	Dimension (mm)
	W	8.00±0.30
	P0	4.00±0.10
	P1	4.00±0.10
	P2	2.00±0.10
	D0	Φ1.55±0.10
	D1	Φ1.00±0.05
	E	1.75±0.10
	F	3.50±0.10
	A	3.10±0.10
	A0	2.10±0.10
	B	2.75±0.10
	B0	0.65±0.10
	K	1.10±0.10
	t	0.20±0.05
	D	Φ178.0±2.0
	D2	Φ13.0
	W1	9.5
Reel	Quantity: 3000PCS	

Mouser Electronics

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Yageo:

SET23A03L02